

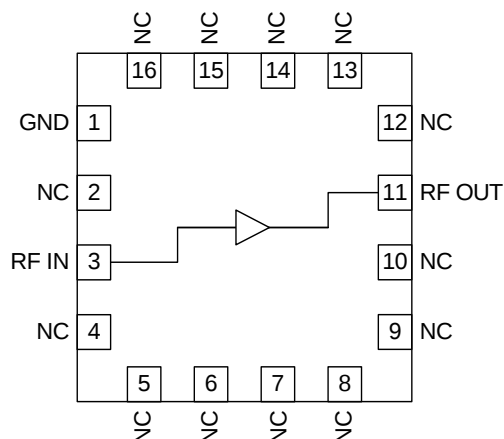
RoHS Compliant & Pb-Free Product
Package Style: QFN, 16-Pin, 3mmx3mm

Features

- 5MHz to 1500MHz Operation
- Internally Matched Input and Output
- 20dB Small Signal Gain
- 1.2dB Noise Figure
- +24dBm Output Power
- Single 5V to 9V Positive Power Supply

Applications

- CATV Distribution Amplifiers
- Cable Modems
- Broadband Gain Blocks
- Laser Diode Driver
- Return Channel Amplifier
- Base Stations



Functional Block Diagram

Product Description

The RF3827 is a general purpose, low-cost, high-linearity RF amplifier IC. The device is manufactured on a Gallium Arsenide process and is featured in a 3mmx3mm, 16-pin, QFN package. It has been designed for use as an easily cascadable 75 Ω gain block with a noise figure of less than 2dB. Gain flatness better than 0.5dB from 5MHz to 1000MHz, and high linearity make this part ideal for cable TV applications. Other applications include IF and RF amplification in wireless voice and data communication products operating in frequency bands up to 1000MHz. The device is self-contained with 75 Ω input and output impedances providing less than 2:1 VSWR matching. For higher input and output return losses, see the evaluation schematic.

Ordering Information

RF3827	Linear General Purpose Amplifier
RF3827 PCBA	Fully Assembled Evaluation Board 50 Ω

Optimum Technology Matching® Applied

- | | | | |
|---|--------------------------------------|-------------------------------------|-----------------------------------|
| ☐ GaAs HBT | ☐ SiGe BiCMOS | ☐ GaAs pHEMT | ☐ GaN HEMT |
| ☒ GaAs MESFET | ☐ Si BiCMOS | ☐ Si CMOS | |
| ☐ InGaP HBT | ☐ SiGe HBT | ☐ Si BJT | |

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Absolute Maximum Ratings

Parameter	Rating	Unit
Device Current	175	mA
Device Voltage	9	V
Input RF Power	+13	dBm
Output Load VSWR	20:1	
Ambient Operating Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	°C



Caution! ESD sensitive device.

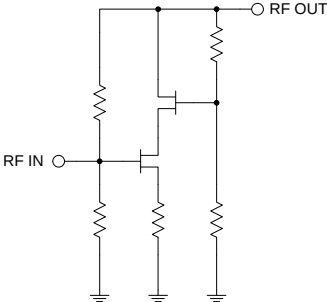
Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective2002/95/EC (at time of this document revision).

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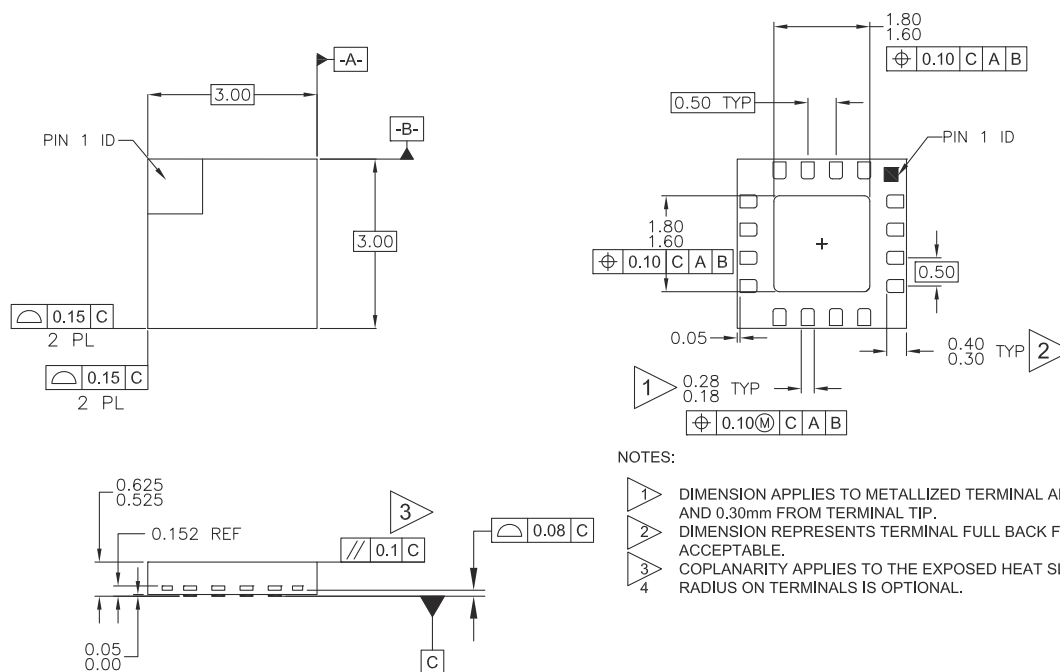
Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Overall (50Ω)					T=25 °C, V _{DD} =7V, 50Ω System, P _{IN} = -8dBm
Frequency Range	5		1500	MHz	3dB Bandwidth
Input VSWR		1.6:1			Appropriate values for the output DC blocking capacitor and bias inductor are required to maintain this VSWR over the intended operating frequency range.
Output VSWR		1.2:1			See note for Input VSWR.
Gain		20		dB	At 500MHz
Gain Flatness		+/-0.9		dB	5MHz to 1000MHz
Noise Figure		1.2		dB	At 500MHz
Noise Figure		1.5		dB	From 5MHz to 1000MHz
Output IP ₃		33.7		dBm	At 10MHz, Delta F1 and F2 = 1MHz
Output IP ₃		37.2		dBm	At 500MHz
Output IP ₃		36.4		dBm	At 1000MHz
Output IP ₂		46.3		dBm	At 100MHz, Delta F1 and F2 = 156MHz
Output IP ₂		44.4		dBm	At 1000MHz
Output P _{1dB}		21		dBm	At 10MHz
Output P _{1dB}		24		dBm	At 500MHz
Output P _{1dB}		23.7		dBm	At 1000MHz
Reverse Isolation		24		dB	At 500MHz
					T=25 °C, V _{DD} =9V, P _{IN} = -8dBm
Gain		20		dB	At 500MHz
Gain Flatness		+/-0.9		dB	5MHz to 1000MHz
Noise Figure		1.1		dB	At 500MHz
Noise Figure		1.5		dB	From 5MHz to 1000MHz,
Output IP ₃		34.8		dBm	At 10MHz, Delta F1 and F2 = 1MHz
Output IP ₃		38.1		dBm	At 500MHz
Output IP ₃		38.7		dBm	At 1000MHz
Output IP ₂		44.1		dBm	At 100MHz, Delta F1 and F2 = 156MHz
Output IP ₂		48.6		dBm	At 1000MHz
Output P _{1dB}		22.5		dBm	At 10MHz
Output P _{1dB}		25.1		dBm	At 500MHz
Output P _{1dB}		25.3		dBm	At 1000MHz

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Power Supply					
Supply Voltage (V _{DD})	6	7	9	V	
Overall (75Ω)					T=25°C, V _{DD} = 7V, 75Ω System, P _{IN} =-8dBm
Frequency Range	5		1500	MHz	3dB Bandwidth
Input VSWR		1.6:1			Appropriate values for the output DC blocking capacitor and bias inductor are required to maintain this VSWR over the intended operating frequency range.
Output VSWR		1.3:1			See note for input VSWR.
Gain		20		dB	At 500MHz
Gain Flatness		±0.5		dB	5MHz to 1000MHz
Output IP ₃		36.8		dBm	At 50MHz, Delta F1 and F2 = 1 MHz
		36.0		dBm	At 500MHz
Output IP ₂		50.1		dBm	At 500MHz, Delta F1 and F2 = 55.25MHz
Output IP _{1dB}		21		dBm	At 10MHz
		23		dBm	At 500MHz
		22		dBm	At 1000MHz
Operating Current Range	100	104	109	mA	
110 Channels					10dBmV per channel, flat, at the input of the amplifier; V _{CC} = 7V, I _{CC} = 120mA
CTB		-75		dBc	At 55.25MHz
		-77		dBc	At 331.25MHz
		-75		dBc	At 547.25MHz
CSO+1.25MHz		-91		dBc	At 55.25MHz
		-60		dBc	At 331.25MHz
		-57		dBc	At 547.25MHz
CSO-1.25MHz		-55		dBc	At 55.25MHz
		-54		dBc	At 331.25MHz
		-56		dBc	At 547.25MHz
CNR		+66		dB	At 55.25MHz
		+65		dB	At 331.25MHz
		+65		dB	At 547.25MHz
Power Supply					
Supply Voltage (V _{DD})	6	7	9	V	
Operating Current Range	115	120	130	mA	

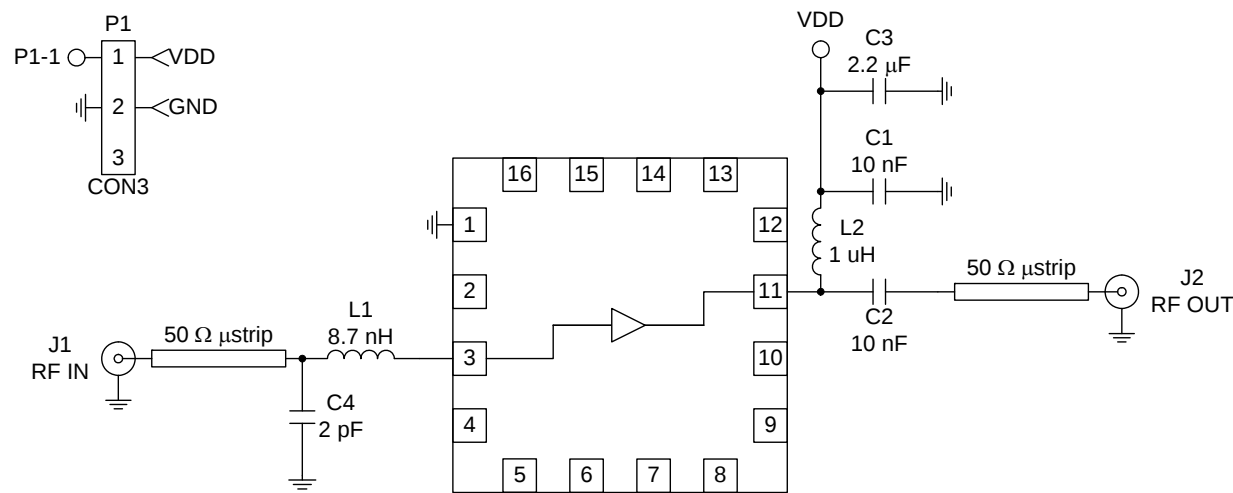
Pin	Function	Description	Interface Schematic
1	GND	Keep traces physically short. Connect this pin to the ground plane with a via.	
2	NC	No connection. This pin should be connected to the ground plane.	
3	RF IN	RF input pin. This pin is internally DC blocked. An external DC blocking capacitor is not required.	
4	NC	No connection. This pin should be connected to the ground plane.	
5	NC	No connection. This pin should be connected to the ground plane.	
6	NC	No connection. This pin should be connected to the ground plane.	
7	NC	No connection. This pin should be connected to the ground plane.	
8	NC	No connection. This pin should be connected to the ground plane.	
9	NC	No connection. This pin should be connected to the ground plane.	
10	NC	No connection. This pin should be connected to the ground plane.	
11	RF OUT	RF output and bias pin. Because DC is present on this pin, a DC blocking capacitor, suitable for the frequency of operation, should be used in most applications. For biasing, only an RF choke is needed.	
12	NC	No connection. This pin should be connected to the ground plane.	
13	NC	No connection. This pin should be connected to the ground plane.	
14	NC	No connection. This pin should be connected to the ground plane.	
15	NC	No connection. This pin should be connected to the ground plane.	
16	NC	No connection. This pin should be connected to the ground plane.	
Pkg Base	GND		

Package Drawing

Package Style: QFN, 16-Pin, 3mmx3mm



Evaluation Board Schematic - 50Ω



3827400, r.1

Evaluation Board Layout - 50 Ω
Board Size 1.0" x 1.5"
Board Thickness 0.031", Board Material FR-4

